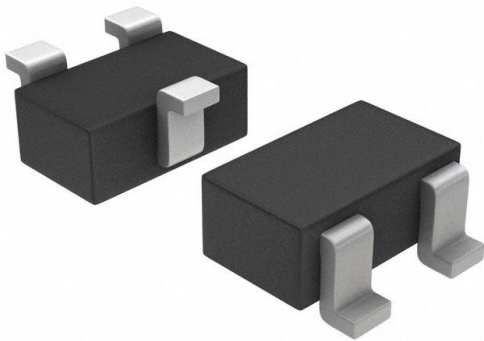


# FJX3015RTF Datasheet

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DiGi Electronics Part Number	FJX3015RTF-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	FJX3015RTF
Description	TRANS PREBIAS NPN 50V SOT323
Detailed Description	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased 50 V 100 mA 250 MHz 200 mW Surface Mount SOT-323



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

FJX3015RTF

Series:

-

Transistor Type:

NPN - Pre-Biased

Voltage - Collector Emitter Breakdown (Max):

50 V

Resistor - Emitter Base (R2):

10 kOhms

Vce Saturation (Max) @ Ib, Ic:

300mV @ 500μA, 10mA

Frequency - Transition:

250 MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-323

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Resistor - Base (R1):

2.2 kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

33 @ 10mA, 5V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

200 mW

Package / Case:

SC-70, SOT-323

Base Product Number:

FJX301

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

REACH Status:

REACH Unaffected

HTSUS:

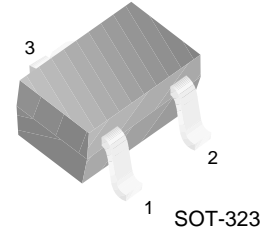
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## FJX3015R

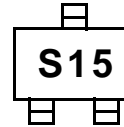
### Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R1=2.2KΩ, R2=10KΩ)

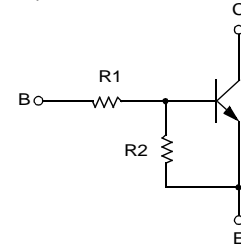


1. Base 2. Emitter 3. Collector

Marking



Equivalent Circuit



### NPN Epitaxial Silicon Transistor

#### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CB0}$	Collector-Base Voltage	50	V
$V_{CEO}$	Collector-Emitter Voltage	50	V
$V_{EBO}$	Emitter-Base Voltage	10	V
$I_C$	Collector Current	100	mA
$P_C$	Collector Power Dissipation	200	mW
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

#### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CB0}$	Collector-Base Breakdown Voltage	$I_C=10\mu\text{A}$ , $I_E=0$	50			V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=100\mu\text{A}$ , $I_B=0$	50			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=40\text{V}$ , $I_E=0$			0.1	$\mu\text{A}$
$h_{FE}$	DC Current Gain	$V_{CE}=5\text{V}$ , $I_C=10\text{mA}$	33			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=10\text{mA}$ , $I_B=0.5\text{mA}$			0.3	V
$f_T$	Current Gain Bandwidth Product	$V_{CE}=10\text{V}$ , $I_C=5\text{mA}$		250		MHz
$C_{ob}$	Output Capacitance	$V_{CB}=10\text{V}$ , $I_E=0$ $f=1.0\text{MHz}$		3.7		pF
$V_{I(off)}$	Input Off Voltage	$V_{CE}=5\text{V}$ , $I_C=100\mu\text{A}$	0.3			V
$V_{I(on)}$	Input On Voltage	$V_{CE}=0.3\text{V}$ , $I_C=20\text{mA}$			3	V
$R_1$	Input Resistor		1.5	2.2	2.9	KΩ
$R_1/R_2$	Resistor Ratio		0.20	0.22	0.25	

# Typical Characteristics

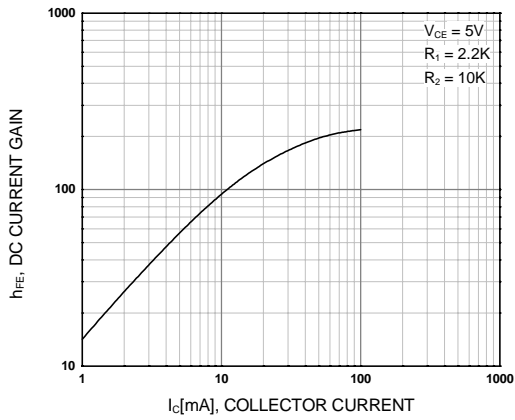


Figure 1. DC current Gain

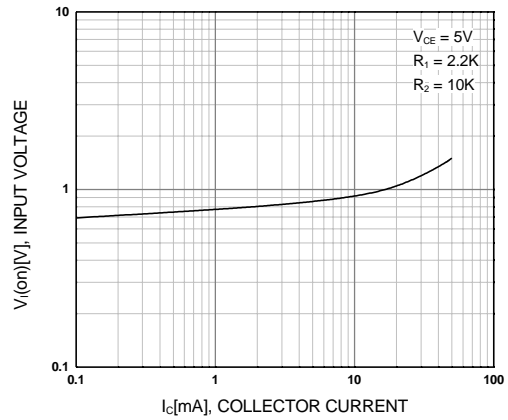


Figure 2. Input On Voltage

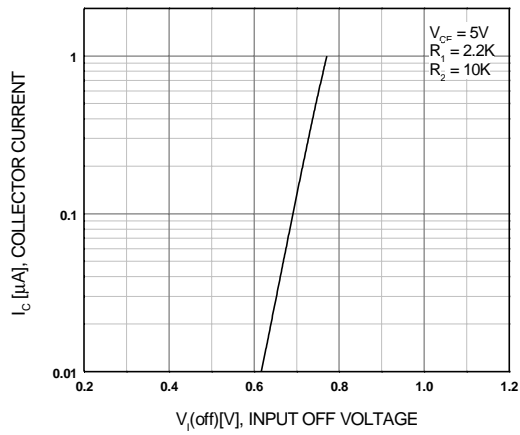


Figure 3. Input Off Voltage

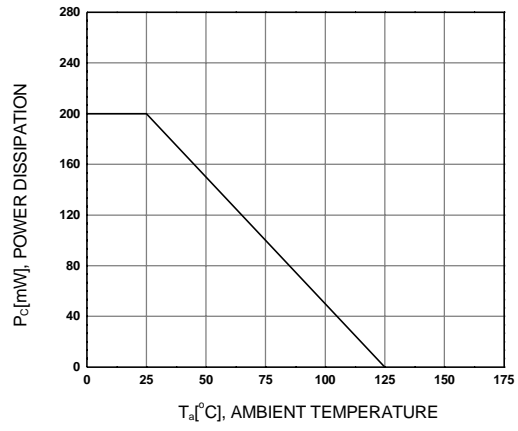
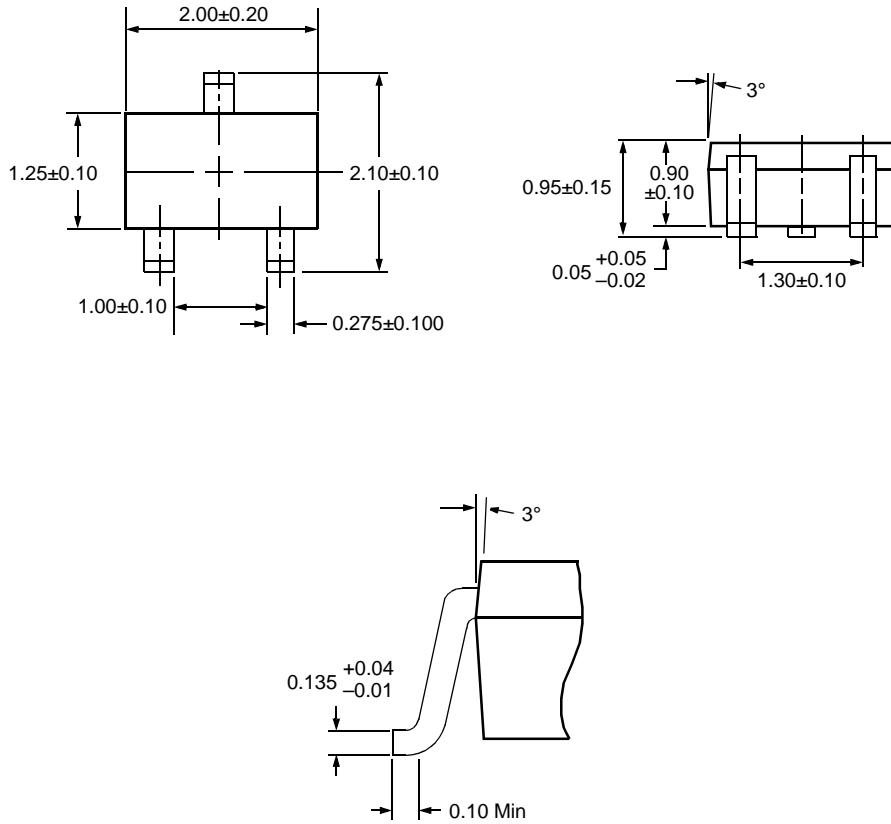


Figure 4. Power Derating

Package Dimensions

SOT-323



Dimensions in Millimeters

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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